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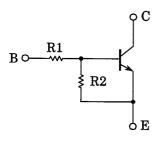
TOSHIBA Transistor Silicon NPN Epitaxial Type (PCT Process)

### RN1901,RN1902,RN1903 RN1904,RN1905,RN1906

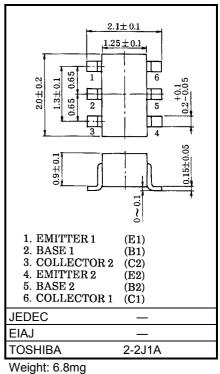
# Switching, Inverter Circuit, Interface Circuit And Driver Circuit Applications

- Including two devices in US6 (ultra super mini type with 6 leads)
- With built-in bias resistors
- Simplify circuit design
- Reduce a quantity of parts and manufacturing process
- Complementary to RN2901~RN2906

### **Equivalent Circuit and Bias Resistor Values**



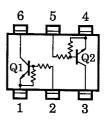
Type No.	R1 (kΩ)	R2 (kΩ)			
RN1901	4.7	4.7			
RN1902	10	10			
RN1903	22	22			
RN1904	47	47			
RN1905	2.2	47			
RN1906	4.7	47			



### Equivalent Circuit (Top View)

### Maximum Ratings (Ta = 25°C) (Q1, Q2 Common)

Characteristi	Symbol	Rating	Unit		
Collector-base voltage	RN1901~1906	V <sub>CBO</sub>	50	V	
Collector-emitter voltage	KN1901-1900	V <sub>CEO</sub>	50	V	
Emitter-base voltage	RN1901~1904	V <sub>EBO</sub>	10	V	
Emilier-base voltage	RN1905, 1906	▲EBO	5		
Collector current		۱ <sub>C</sub>	I <sub>C</sub> 100		
Collector power dissipation	RN1901~1906	P <sub>C</sub> *	200	mW	
Junction temperature	101301-1900	Tj	150	°C	
Storage temperature range		T <sub>stg</sub>	-55~150	°C	



\*: Total rating

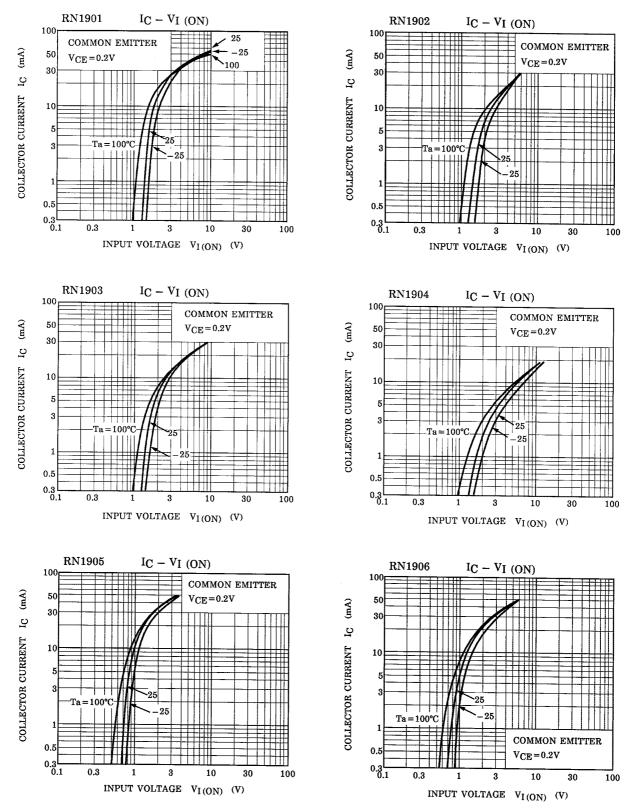
Unit: mm

## Electrical Characteristics (Ta = 25°C) (Q1, Q2 Common)

Characteristic		Symbol	Test Circuit	Test Condition	Min	Тур.	Max	Unit
Collector cut-off current	RN1901~1906	I <sub>CBO</sub>	—	V <sub>CB</sub> = 50V, I <sub>E</sub> = 0	-	_	100	nA
	RN 1901~1900	ICEO	_	V <sub>CE</sub> = 50V, I <sub>B</sub> = 0	_	_	500	
	RN1901	I <sub>EBO</sub>	—	- V <sub>EB</sub> = 10V, I <sub>C</sub> = 0	0.82	_	1.52	mA
	RN1902		_		0.38	_	0.71	
Fraitten out off oursent	RN1903		_		0.17	_	0.33	
Emitter cut-off current	RN1904		_		0.082	_	0.15	
	RN1905		_	V <sub>EB</sub> = 5V, I <sub>C</sub> = 0	0.078	_	0.145	
	RN1906		_		0.074	_	0.138	
	RN1901	hFE	—		30	_	_	
	RN1902		_		50	_	_	
	RN1903		_	- V <sub>CE</sub> = 5V, I <sub>C</sub> = 10mA	70	_	_	
DC current gain	RN1904		_		80	_	_	
	RN1905		_		80	_	_	
	RN1906		_		80	_	_	
Collector-emitter saturation voltage	RN1901~1906	V <sub>CE (sat)</sub>	_	I <sub>C</sub> = 5mA, I <sub>B</sub> = 0.25mA	_	0.1	0.3	V
	RN1901		—	- V <sub>CE</sub> = 0.2V, I <sub>C</sub> = 5mA	1.1	_	2.0	V
	RN1902		_		1.2	_	2.4	
	RN1903	V <sub>I (ON)</sub>	_		1.3	_	3.0	
Input voltage (ON)	RN1904		_		1.5	_	5.0	
	RN1905		_		0.6	_	1.1	
	RN1906		_		0.7	_	1.3	
	RN1901~1904	V <sub>I (OFF)</sub>	—	V <sub>CE</sub> = 5V, I <sub>C</sub> = 0.1mA	1.0	_	1.5	v
Input voltage (OFF)	RN1905, 1906		_		0.5	_	0.8	
Translation frequency	RN1901~1906	f <sub>T</sub>	—	V <sub>CE</sub> = 10V, I <sub>C</sub> = 5mA	—	250	-	MHz
Collector output capacitance	RN1901~1906	C <sub>ob</sub>	_	V <sub>CB</sub> = 10V, I <sub>E</sub> = 0, f = 1MHz	_	3	6	pF
	RN1901	R1	—		3.29	4.7	6.11	kΩ
	RN1902		_		7	10	13	
la su de sa a la de sa	RN1903		_		15.4	22	28.6	
Input resistor	RN1904		_		32.9	47	61.1	
	RN1905		_		1.54	2.2	2.86	
	RN1906		_		3.29	4.7	6.11	
	RN1901~1904	R1/R2	_		0.9	1.0	1.1	
Resistor ratio	RN1905		_		0.0421	0.0468	0.0515	
	RN1906		_		0.09	0.1	0.11	

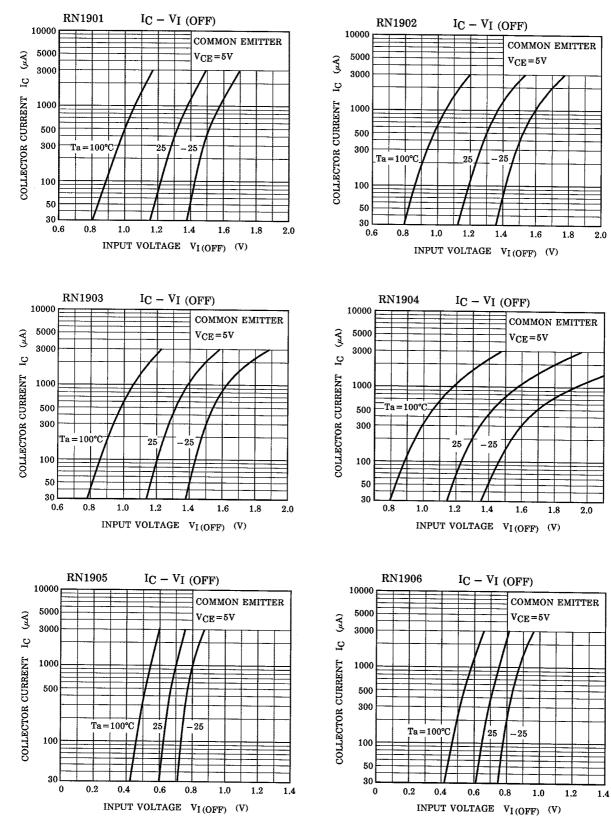
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#### (Q1, Q2 Common)

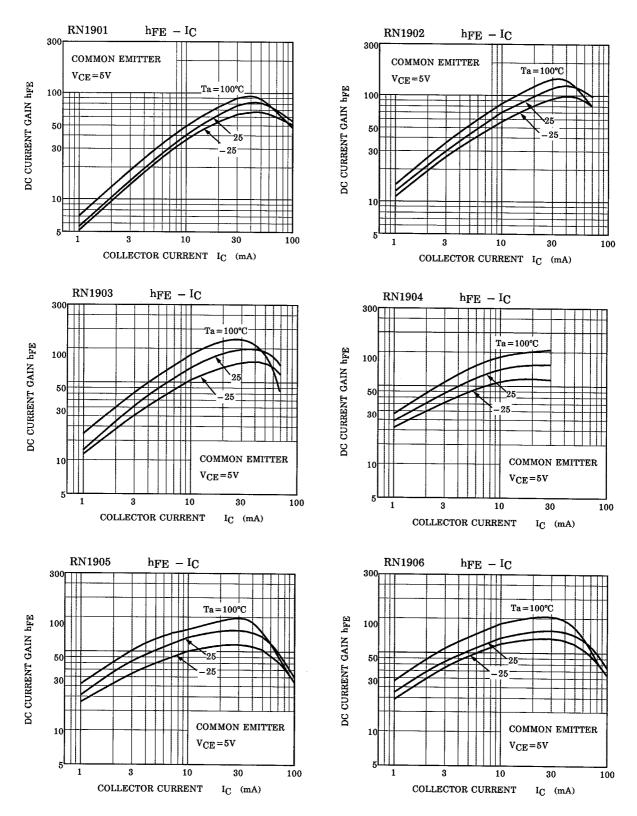


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#### (Q1, Q2 Common)



(Q1, Q2 Common)



Type Name	Marking
RN1901	Type Name REA X A BBB
RN1902	Type Name X B UUU
RN1903	Type Name EEE X C EEE
RN1904	Type Name EEE X D EEE
RN1905	Type Name X E
RN1906	Type Name X F UUU

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